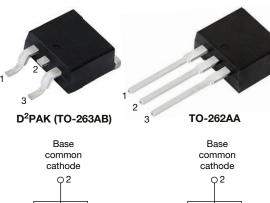
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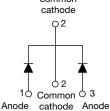
Vishay Semiconductors

High Performance Schottky Rectifier, 2 x 20 A





SHAY



Anode cathode Anode

VS-42CTQ030-1-M3

PRIMARY CHARACTERISTICS								
I _{F(AV)}	2 x 20 A							
V _R	30 V							
V _F at I _F	0.38 V							
I _{RM}	183 mA at 125 °C							
T _J max.	150 °C							
E _{AS}	13 mJ							
Package	D ² PAK (TO-263AB), TO-262AA							
Circuit configuration	Common cathode							

FEATURES

- 150 °C T_J operation
- · Center tap configuration
- Very low forward voltage drop
- High frequency operation



HALOGEN

FREE

- Guard ring for enhanced ruggedness and long term reliability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 $^{\circ}\mathrm{C}$
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier module has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	40	А						
V _{RRM}		30	V						
I _{FSM}	t _p = 5 μs sine	1100	A						
V _F	20 A_{pk} , T_J = 125 °C (per leg)	0.38	V						
TJ	Range	-55 to +150	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-42CTQ030S-M3 VS-42CTQ030-1-M3	UNITS						
Maximum DC reverse voltage	V _R	30	V						
Maximum working peak reverse voltage	V _{RWM}	55	v						

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VS-42CTQ030S-M3, VS-42CTQ030-1-M3

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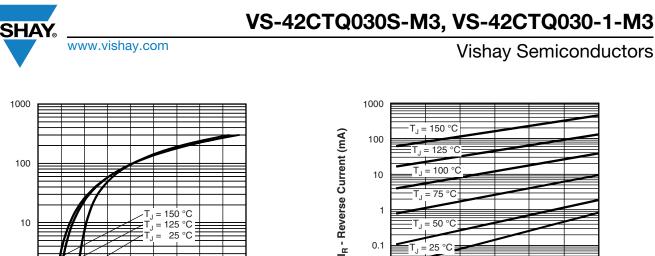
ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST COND	VALUES	UNITS			
Maximum average	per leg			20				
forward current See fig. 5	per device	I _{F(AV)}	50 % duty cycle at T_{C} = 121 °C	40				
Maximum peak one cycle r	on-repetitive		5 µs sine or 3 µs rect. pulse Following any rated loa		1100	A		
surge current per leg See fig. 7		I _{FSM}	10 ms sine or 6 ms rect. pulse Condition and with rated V _{RRM} applied		360			
Non-repetitive avalanche energy per leg E _{AS}		E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 2.90 mH		13	mJ		
Repetitive avalanche currer	nt per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3	А		

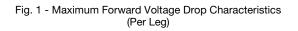
ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CC	NDITIONS	VALUES	UNITS				
		20 A	T _{.1} = 25 °C	0.48	V				
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	40 A	$-1_{j}=25$ C	0.57					
See fig. 1	VFM ()	20 A	– T.I = 125 °C	0.38					
		40 A	1j = 125 C	0.51					
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V - Reted V	3	mA				
See fig. 2	IRM ("	T _J = 125 °C	- V _R = Rated V _R	183					
Threshold Voltage	V _{F(TO)}			0.22	V				
Forward slope resistance	r _t	$T_J = T_J maximum$		6.76	mΩ				
Maximum junction capacitance per leg	CT	V _R = 5 V _{DC} (test signal rang	2840	pF					
Typical series inductance per leg	L _S	Measured lead to lead 5 m	8.0	nH					
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs					

Note

⁽¹⁾ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to 150	°C			
Maximum thermal resistance, junction to case per leg		P	DC operation	2.0	°C/W			
Maximum thermal resistance, junction to case per package		R _{thJC}		1.0				
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50				
Approvimento woight				2	g			
Approximate weight				0.07	oz.			
minimum				6 (5)	kgf ⋅ cm			
Mounting torque	maximum			12 (10)	(lbf ⋅ in)			
Marking davias			Case style D ² PAK (TO-263AB)	42CT0	2030S			
Marking device			Case style TO-262AA	42CTC	2030-1			





V_{FM} - Forward Voltage Drop (V)

1.0

0.8

0.4 0.6 = 150 °C

= 125 °C

25 °C = =

1.2 1.4 1.6

1.8

I_F - Instantaneous Forward Current (A)

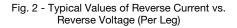
100

10

0

0.2

100 = 125 °C = 100 °C 10 = 75 °C 1 = 50 °C 0.1 25 °C 0.01 5 10 15 20 25 30 0 V_R - Reverse Voltage (V)



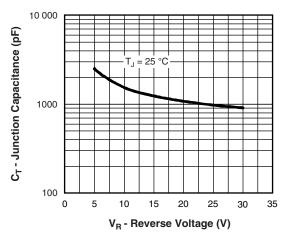
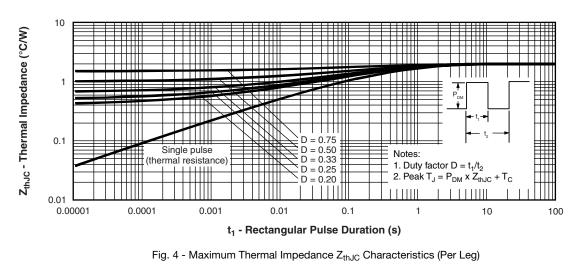


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

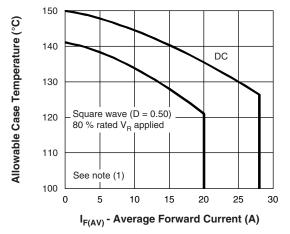


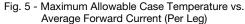
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VS-42CTQ030S-M3, VS-42CTQ030-1-M3

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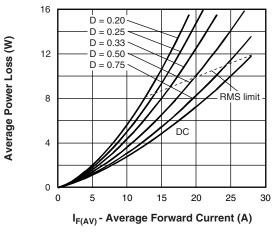


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

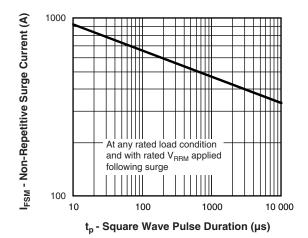


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

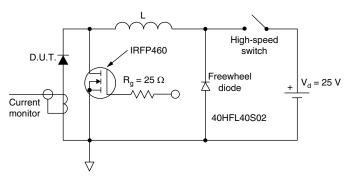


Fig. 8 - Unclamped Inductive Test Circuit

Note

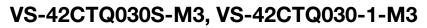
- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- $\begin{array}{l} \mbox{Pd} = \mbox{forward power loss} = \mbox{I}_{F(AV)} \times \mbox{V}_{FM} \mbox{ at } (\mbox{I}_{F(AV)}/D) \mbox{ (see fig. 6);} \\ \mbox{Pd}_{REV} = \mbox{inverse power loss} = \mbox{V}_{R1} \times \mbox{I}_{R} \mbox{ (1 D); } \mbox{I}_{R} \mbox{ at } \mbox{V}_{R1} = \mbox{ 10 V} \end{array}$

Revision: 21-Dec-2021

4

Document Number: 94940

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Vishay Semiconductors

ORDERING INFORMATION TABLE

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VISHAY

Device code	vs-	42	С	т	Q	030	S	TRL	-M3
		(2)	(3)	(4)	(5)	6		(8)	(9)
		\bigcirc	\bigcirc	\bigcirc	Ŭ	\bigcirc	Ċ	C	C
	<u>비</u> ·		-	niconduo	-	oduct			
	2 -								
	3 -	 Circuit configuration: C = common cathode T = TO 220 							
	4 -	T = TO-220							
	5 -	Sch	ottky "G	" series					
	6 -	· Volt	tage rati	ng (030	= 30 V))			
	7 -	• s	= D ² PA	K (TO-2	263AB)				
		• -1	= TO-2	62AA					
	8 -	• N	one = tu	ibe					
		• TI	RL = tap	be and r	eel (left	oriented	d - for D	² PAK (ГО-263
		• TI	RR = ta	pe and r	eel (righ	nt orient	ed - for	D ² PAK	(TO-26
	9 -			gen-free					

ORDERING INFORMATION									
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION							
VS-42CTQ030S-M3	50	Antistatic plastic tubes							
VS-42CTQ030STRL-M3	800	13" diameter plastic tape and reel							
VS-42CTQ030STRR-M3	800	13" diameter plastic tape and reel							
VS-42CTQ030-1-M3	50	Antistatic plastic tubes							

LINKS TO RELATED DOCUMENTS								
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164						
	TO-262AA	www.vishay.com/doc?96165						
Part marking information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444						
	TO-262AA	www.vishay.com/doc?95443						
Packaging information		www.vishay.com/doc?96424						

Outline Dimensions



D²PAK

DIMENSIONS in millimeters and inches

www.vishay.com

SHA



SYMBOL	MILLIM	IETERS	INC	HES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 08-Jul-15

1

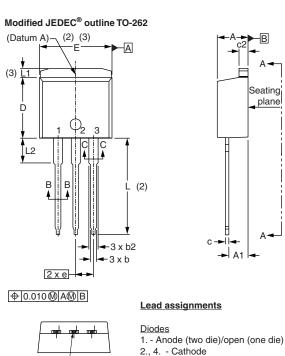
Outline Dimensions



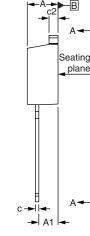
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TO-262

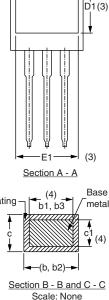
DIMENSIONS in millimeters and inches



Lead tip -



E1 Plating



Е

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. А 4.06 4.83 0.160 0.190 2.03 A1 3.02 0.080 0.119 b 0.51 0.99 0.020 0.039 b1 0.51 0.89 0.020 0.035 4 b2 1.14 1.78 0.045 0.070 1.14 1.73 0.045 0.068 4 b3 0.38 0.74 0.015 0.029 С 0.38 0.58 0.015 0.023 4 c1 1.14 1.65 0.045 0.065 c2 D 8.51 9.65 0.335 0.380 2 D1 6.86 8.00 0.270 0.315 3 Е 9.65 10.67 0.380 0.420 2, 3 E1 7.90 8.80 0.311 0.346 3 0.100 BSC 2.54 BSC е L 13.46 14.10 0.530 0.555 L1 _ 1.65 0.065 3 _ 3.36 0.132 0.146 L2 3.71

3. - Anode

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

Outline conform to JEDEC TO-262 except A1 (maximum), (6) b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

Revision: 11-Jul-2019

Document Number: 95419

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